

RV1S9060A

R08DS0168EJ0100

Rev.1.00

HIGH CMR, 15Mbps CMOS OUTPUT, LOW FORWARD-CURRENT(IF) 3.3V/5V OPERATION, 5-PIN with 8mm creepage distance package LSO5 PHOTOCOUPLER

Jun 4, 2019

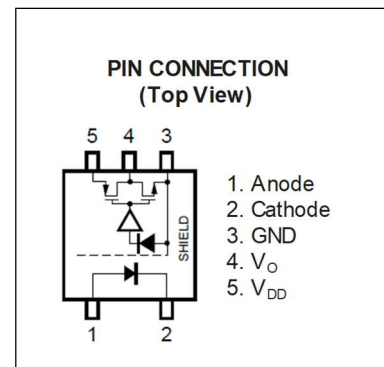
DESCRIPTION

The RV1S9060A is a photocoupler featuring high-speed switching up to 15Mbps with active low output logic which consist of an AlGaAs LED on the input side and an integrated circuit with a photodiode on the output.

This product enables to low current operation on 3.3V/5V power supply with high noise-tolerant CMR:50kV/us min. and high temperature operation up to Ta=125°C in logic interface circuit.

FEATURES

- Long creepage distance (8 mm MIN)
- High speed communication (15 Mbps)
- High temperature operation (-40 to +125°C)
- High common mode (dv/dt) tolerant (CM_H, CM_L = ±50 kV/μs MIN.)
- High isolation voltage (BV = 5000 Vr.m.s.)
- Low input drive current (IFHL = 2.2 mA MAX.)
- Low voltage power supply operation (VDD = 2.7 V~5.5 V)
- Low pulse width distortion (PWD = 20 ns MAX.)
- Ordering number of tape product :
RV1S9060ACCSP-10Yx#KC0 : 3000pcs/reel
- Pb free product
- Safety standards approval
UL : UL1577, Double protection
CSA : CAN/CSA-C22.2 No.62368-1, Reinforced insulation
VDE : DIN EN 60747-5-5 (Option)



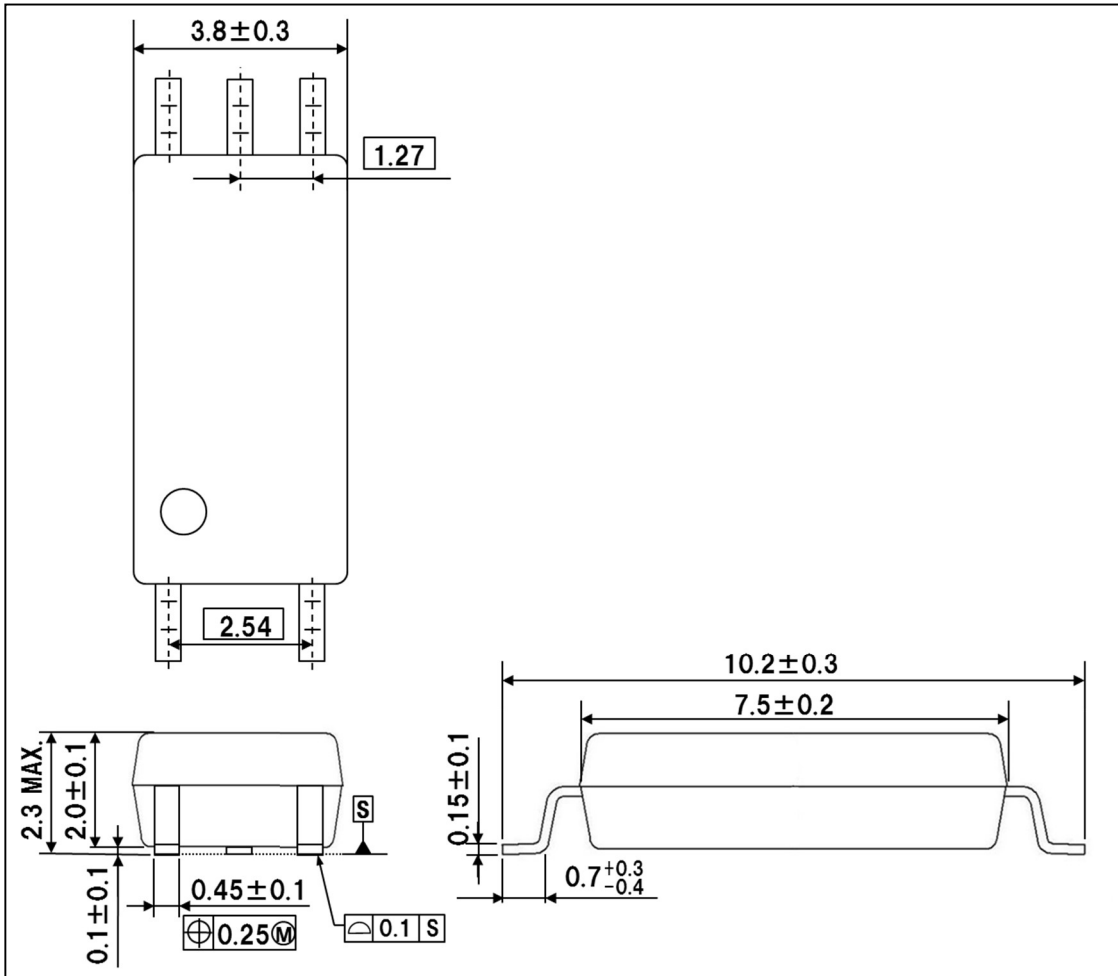
APPLICATIONS

- FA Network
- Measurement, Control Equipment (Inverter, AC Servo)

TRUTH TABLE

LED	OUTPUT
ON	L
OFF	H

PACKAGE DIMENSIONS (UNIT : mm)



Weight : 0.119g (typ.)

PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	8.0 mm
Outer Creepage Distance	8.0 mm
Isolation Distance	0.15 mm

MARKING EXAMPLE



*Applicable type numbers are listed below.

*1) RV1S[9060]ACCSP-10Yx

Marking type number. "RV1S" and "ACCSP-10Yx" are omitted from original type number.

ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
RV1S9060ACCSP-10YC	RV1S9060ACCSP-10YC#KC0	Pb-Free and Halogen Free (Ni/Pd/Au)	Embossed Tape 3 000 pcs/reel	Standard products (UL, CSA approved)	RV1S9060A
RV1S9060ACCSP-10YV	RV1S9060ACCSP-10YV#KC0		Embossed Tape 3 000 pcs/reel	UL, CSA, DIN EN 60747-5-5 approved	

Notes: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTELY MAXIMUM RATINGS (TA=25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current *1	IF	20	mA
	Reverse Voltage	VR	5	V
Detector	Supply Voltage	VDD	6	V
	Output Voltage	VO	6	V
	Output Current	IO	10	mA
	Power Dissipation *2	PC	250	mW
Isolation Voltage *3		BV	5 000	Vr.m.s.
Operating Ambient Temperature		TA	-40 to +125	°C
Storage Temperature		Tstg	-55 to +150	°C

Notes: 1. Reduced to 0.93mA/°C at TA=110°C or more
 2. Reduced to 5.25mW/°C at TA=85°C or more
 3. AC Voltage for 1minite at TA=25°C, RH=60% between input and output.
 Pins 1-2 shorted together, 3-5 shorted together.

RECOMMENDED OPERATING CONDITIONS

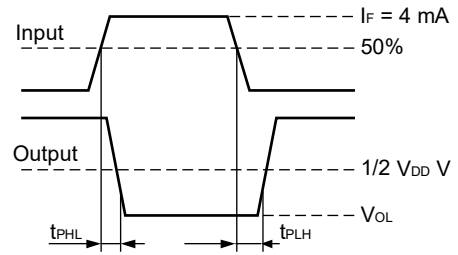
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Low Level forward voltage	V_{FL}	0		0.8	V
High Level Forward Current	I_{FH}	3		6	mA
Supply Voltage	V_{DD}	2.7		5.5	V

ELECTRICAL CHARACTERISTICS

(T_A = -40 to +125°C, V_{DD} = 2.7 to 5.5 V, unless otherwise specified)

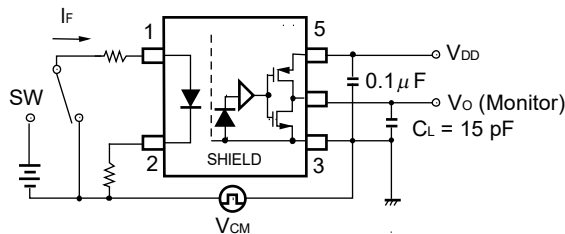
Parameter		Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	V_F	$I_F = 6 \text{ mA}$, $T_A = 25^\circ\text{C}$	1.4	1.55	1.7	V
	Reverse Current	I_R	$V_R = 3 \text{ V}$, $T_A = 25^\circ\text{C}$			10	μA
	Terminal Capacitance	C_t	$V_F = 0 \text{ V}$, $f = 1 \text{ MHz}$, $T_A = 25^\circ\text{C}$		30		pF
Detector	High Level Output Current	I_{DDH}	$I_F = 0 \text{ mA}$		1.1	2	mA
	Low Level Output Current	I_{DDL}	$I_F = 4 \text{ mA}$		1.0	2	mA
	High Level Output Voltage	V_{OH}	$I_O = -3.2 \text{ mA}$, $I_F = 0 \text{ mA}$	$V_{DD}-1.0$	V_{DD}		V
			$I_O = -20 \mu\text{A}$, $I_F = 0 \text{ mA}$	$V_{DD}-0.1$	V_{DD}		
	Low Level Output Voltage	V_{OL}	$I_O = 3.2 \text{ mA}$, $I_F = 4 \text{ mA}$		0.13	0.4	V
$I_O = 20 \mu\text{A}$, $I_F = 4 \text{ mA}$				0.001	0.1		
Coupled	Threshold Input Voltage (H to L)	I_{FHL}	$V_O < 0.4 \text{ V}$		1.2	2.2	mA
	Propagation Delay Time (H to L) ^{*2}	t_{PHL}	$I_F = 4 \text{ mA} \leftrightarrow 0 \text{ mA}$ $V_{DD} = 3.3 \text{ V}, 5 \text{ V}$ $C_L = 15 \text{ pF}$		36	60	ns
	Propagation Delay Time (L to H) ^{*2}	t_{PLH}			38	60	
	Pulse Width Distortion ^{*2}	PWD			2	20	
	Propagation Delay Skew	t_{PSK}				25	
	Rise Time	t_r			5		
	Fall Time	t_f			5		
	Common Mode Transient Immunity at High Level Output ^{*3}	CM_H		$I_F = 0 \text{ mA}$, $V_O > 4 \text{ V}$ ($V_{DD} = 5 \text{ V}$), $V_O > 2.3 \text{ V}$ ($V_{DD} = 3.3 \text{ V}$), $V_{CM} = 1.5 \text{ kV}$, $T_A = 25^\circ\text{C}$	50	60	
	Common Mode Transient Immunity at Low Level Output ^{*3}	CM_L	$I_F = 4 \text{ mA}$, $V_O < 0.4 \text{ V}$ ($V_{DD} = 3.3 \text{ V}, 5 \text{ V}$), $V_{CM} = 1.5 \text{ kV}$, $T_A = 25^\circ\text{C}$	50	60		

- Note2: 1. Typical values at $T_A = 25^\circ\text{C}$
 2. Test circuit for propagation delay time measurement



Remark C_L includes probe and stray wiring capacitance.

3. Test circuit for common mode transient immunity measurement

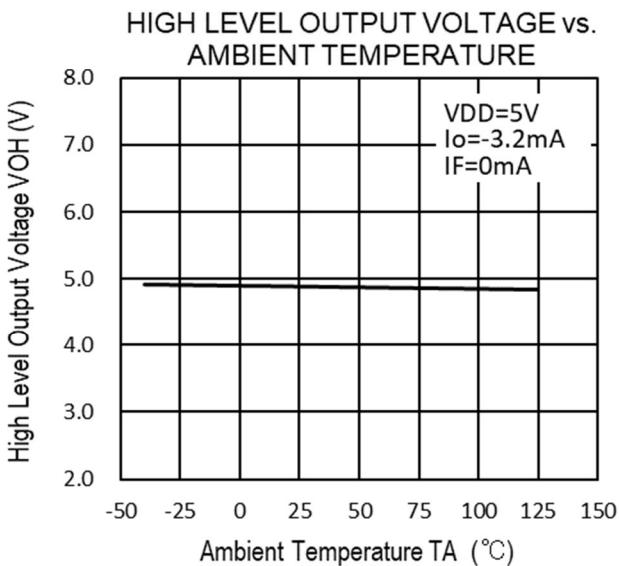
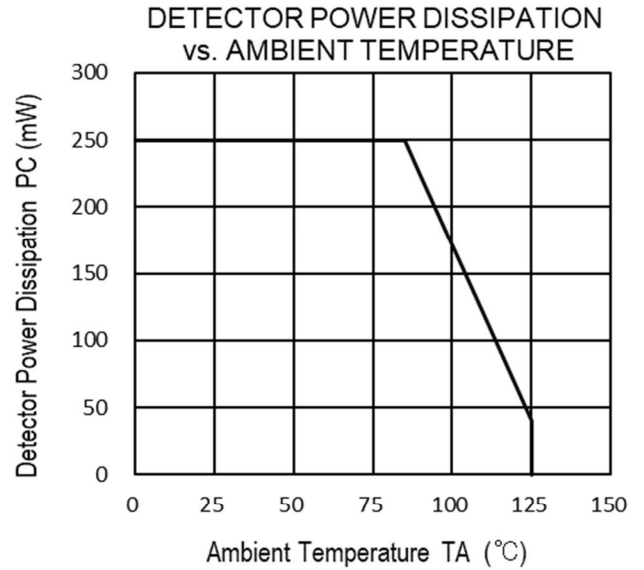


Remark C_L includes probe and stray wiring capacitance.

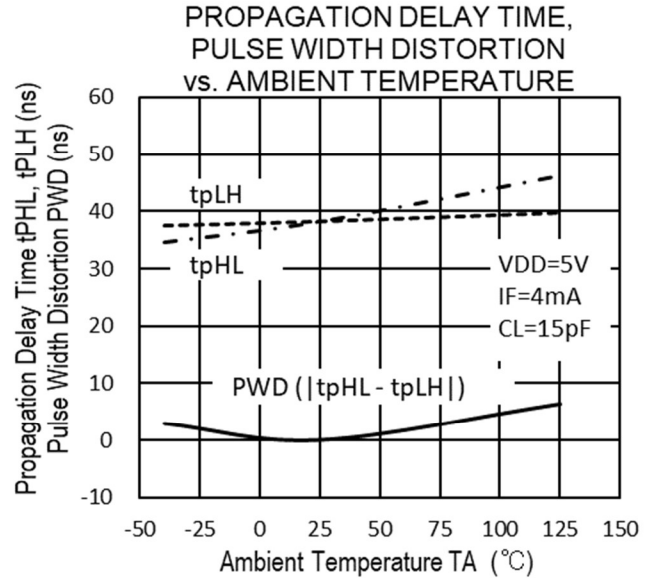
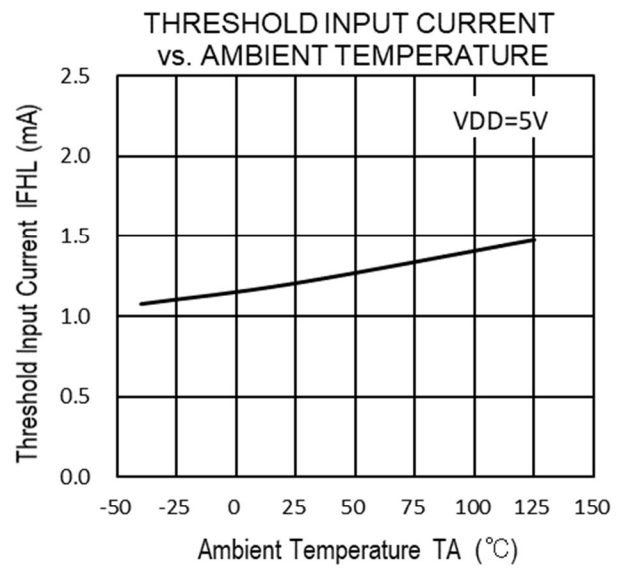
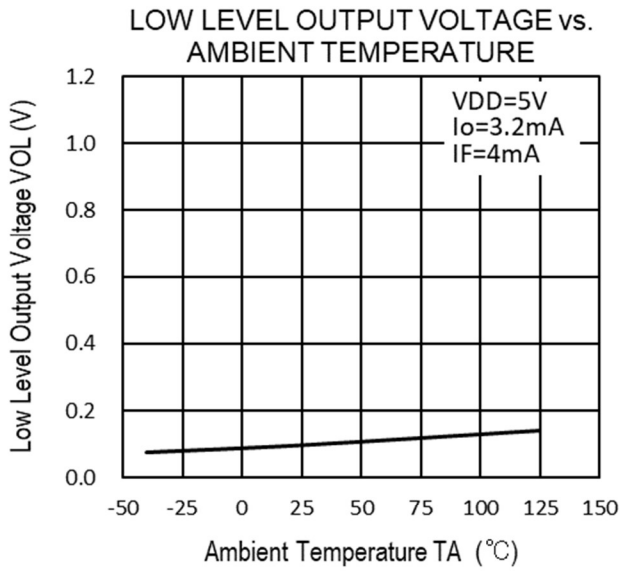
USAGE CAUTIONS

1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
2. By-pass capacitor of more than $0.1 \mu\text{F}$ is used between V_{DD} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
3. Avoid storage at a high temperature and high humidity.

TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)



Remark The graphs indicate nominal characteristics.



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TAPING SPECIFICATIONS (UNIT : mm)

Taping Direction



Outline and Dimensions (Tape)

Unit: mm



Outline and Dimensions (Reel)

Unit: mm



Packing: 3 000 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT : mm)



NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

- Peak Temperature (lead part temperature) 350°C or below
- Time (each pins) 3 seconds or less
- Flux Rosin flux containing small amount of chlorine
(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

- Flux Cleaning
Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- Do not use adhesives or coating materials including halogens to fix this device.

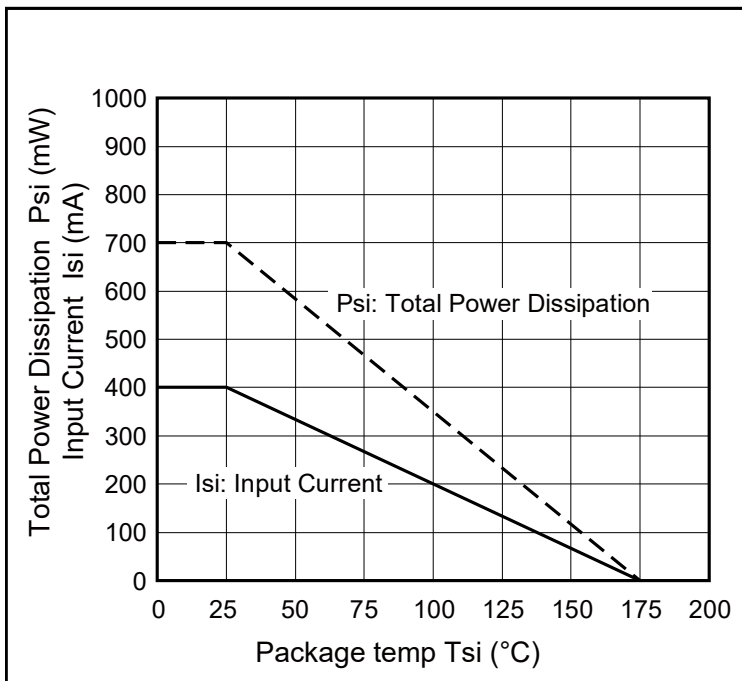
2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

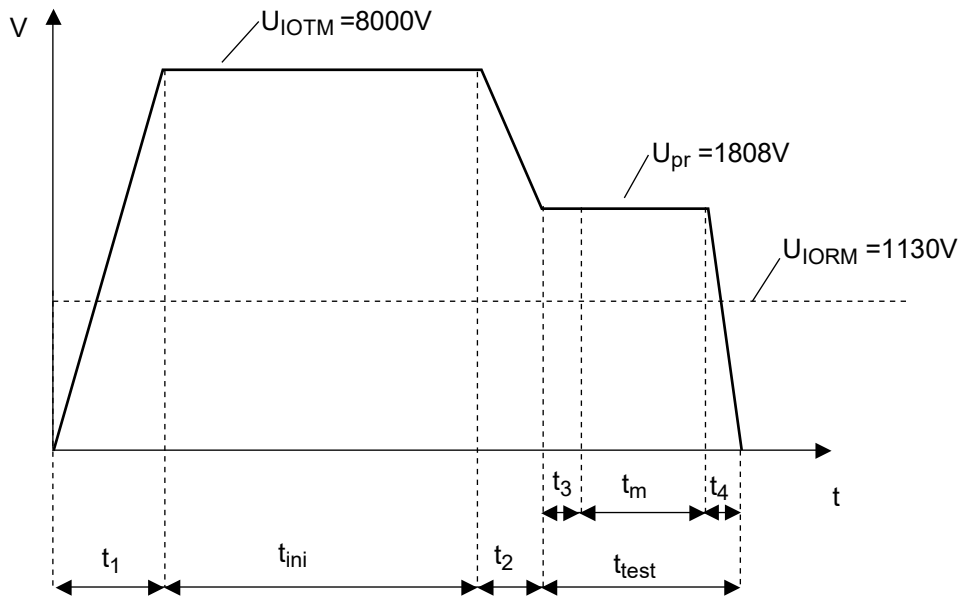
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{IORM}, P_d < 5 \text{ pC}$	U_{IORM} U_{pr}	1 130 1 808	V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) $U_{pr} = 1.875 \times U_{IORM}, P_d < 5 \text{ pC}$	U_{pr}	2 119	V_{peak}
Highest permissible overvoltage	U_{IOTM}	8 000	V_{peak}
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	CTI	400	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		II	
Storage temperature range	T_{stg}	-55 to +150	°C
Operating temperature range	T_A	-40 to +125	°C
Isolation resistance, minimum value $V_{IO} = 500 \text{ V dc at } T_A = 25^\circ\text{C}$ $V_{IO} = 500 \text{ V dc at } T_A \text{ MAX. at least } 100^\circ\text{C}$	Ris MIN. Ris MIN.	10^{12} 10^{11}	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F , $P_{si} = 0$) Power (output or total power dissipation) Isolation resistance $V_{IO} = 500 \text{ V dc at } T_A = T_{si}$	T_{si} I_{si} P_{si} Ris MIN.	175 400 700 10^9	°C mA mW Ω

Dependence of maximum safety ratings with package temperature



Method a) Destructive Test, Type and Sample Test



$t_1, t_2 = 1 \text{ to } 10 \text{ sec}$
 $t_3, t_4 = 1 \text{ sec}$
 $t_m(\text{PARTIAL DISCHARGE}) = 10 \text{ sec}$
 $t_{\text{test}} = 12 \text{ sec}$
 $t_{\text{ini}} = 60 \text{ sec}$

Method b) Non-destructive Test, 100% Production Test



$t_3, t_4 = 0.1 \text{ sec}$
 $t_m(\text{PARTIAL DISCHARGE}) = 1.0 \text{ sec}$
 $t_{\text{test}} = 1.2 \text{ sec}$

Caution	GaAs Products	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none">• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.<ol style="list-style-type: none">1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.• Do not burn, destroy, cut, crush, or chemically dissolve the product.• Do not lick the product or in any way allow it to enter the mouth.
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